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FJP1943 PNP Epitaxial Silicon Transistor

Applications

- High-Fidelity Audio Output Amplifier
- General Purpose Power Amplifier

Features

- High Current Capability: I_C = -15A.
- High Power Dissipation : 80watts.
- High Frequency : 30MHz.
- High Voltage : V_{CEO}= -230V
- Wide S.O.A for reliable operation.
- Excellent Gain Linearity for low THD.
- Complement to FJP5200

. .

T_J, T_{STG}

- Full thermal and electrical Spice models are available.
 - Same transistor is also available in:
 - -- TO264 package, 2SA1943/FJL4215 : 150 watts
 - -- TO3P package, 2SA1962/FJA4213 : 130 watts
 - -- TO220F package, FJPF1943 : 50 watts

1 TO-220

1.Base 2.Collector 3.Emitter

- 50 ~ +150

Absolute Maximum Ratings [*] $T_a = 25^{\circ}C$ unless otherwise noted				
Symbol	Parameter	Ratings	Units V	
BV _{CBO}	Collector-Base Voltage	-230		
BV _{CEO}	Collector-Emitter Voltage	-230	V	
BV _{EBO}	Emitter-Base Voltage	-5	V	
I _C	Collector Current	-15	А	
I _B	Base Current	-1.5	А	
P _D	Total Device Dissipation(T _C =25°C) Derate above 25°C	80 0.64	W W/°C	

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

$\label{eq:thermal} Thermal \ Characteristics^* \ \ T_a=25^\circ C \ \text{unless otherwise noted}$

Junction and Storage Temperature

Symbol	Parameter	Ratings	Units	
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case	1.25	°C/W	
+ Davids manufacture and size				

Device mounted on minimum pad size

h_{FE} Classification

Classification	R	0
h _{FE1}	55 ~ 110 80 ~ 160	

November 2008

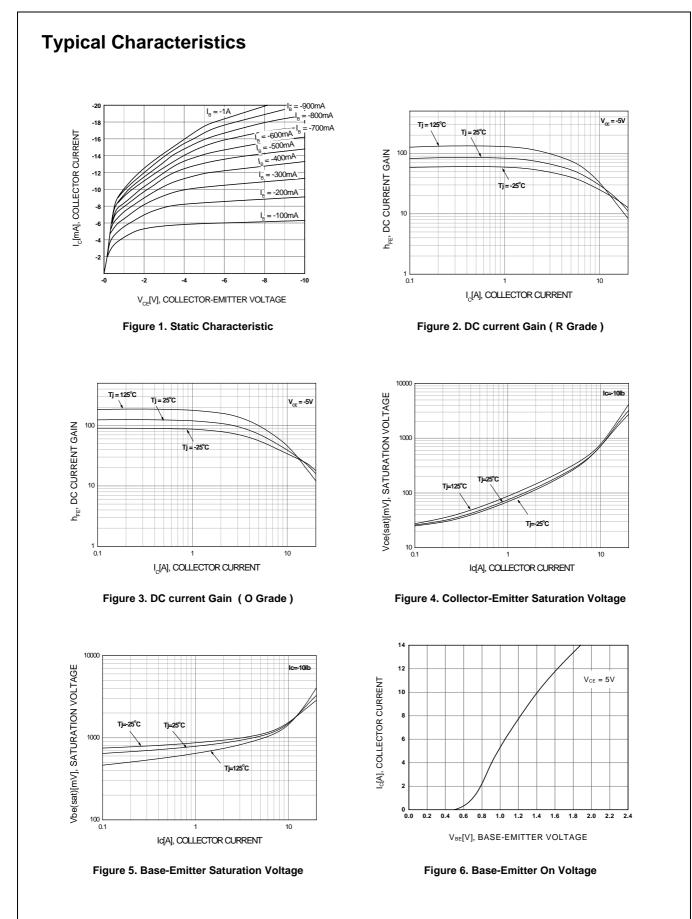
°C

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =-5mA, I _E =0	-230			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I_{C} =-10mA, R_{BE} = ∞	-230			V
BV _{EBO}	Emitter-Base Breakdown Voltage	ter-Base Breakdown Voltage I _E =-5mA, I _C =0				V
I _{CBO}	Collector Cut-off Current	V _{CB} =-230V, I _E =0			-5.0	μΑ
I _{EBO}	Emitter Cut-off Current	V_{EB} =-5V, I _C =0			-5.0	μA
h _{FE1}	DC Current Gain	V _{CE} =-5V, I _C =-1A	55		160	
h _{FE2}	DC Current Gain	V _{CE} =-5V, I _C =-7A	35	60		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =-8A, I _B =-0.8A		-0.4	-3.0	V
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} =-5V, I _C =-7A		-1.0	-1.5	V
f _T	Current Gain Bandwidth Product	V _{CE} =-5V, I _C =-1A		30		MHz
C _{ob}	Output Capacitance	V _{CB} =-10V, f=1MHz		360		pF

* Pulse Test: Pulse Widt=20 $\mu s,$ Duty Cycle≤2%

Ordering Information

Part Number	Marking	Package	Packing Method	Remarks
FJP1943RTU	J1943R	TO-220	TUBE	hFE1 R grade
FJP1943OTU	J1943O	TO-220	TUBE	hFE1 O grade



Typical Characteristics

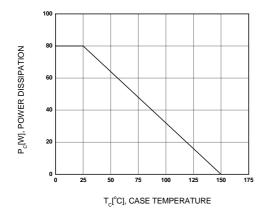


Figure 7. Power Derating

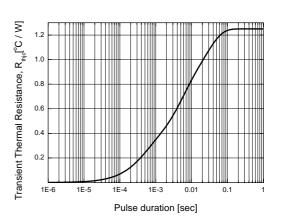


Figure 8. Thermal Resistance





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